

# Fundamentals of High Voltage Techniques

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## ● Generation and measurement of impulse voltages

Impulse voltages are used to simulate internal surge voltages (switching surge) and external surge voltages (lightning surge) and their consequences for different dielectrics (insulators !) of gaseous, liquid or solid origin.

Impulse voltages are normally generated by discharging HV capacitors via spark gaps into “shaping” circuits of resistors and capacitors.

Measurement is accomplished by means of capacitive and/or resistive voltage division and a fast digital oscilloscope with storage facilities.



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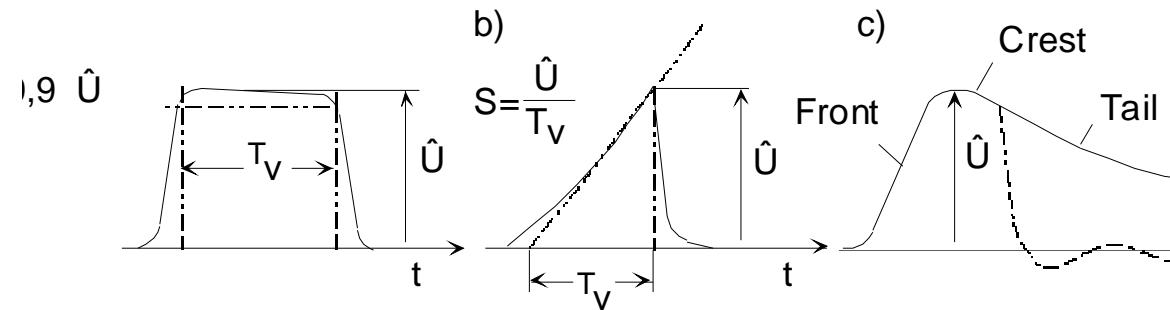
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## ● Rated values for impulse voltages

6 MV

IEG

HV engineering defines an impulse voltage as a single, unipolar voltage impulse.

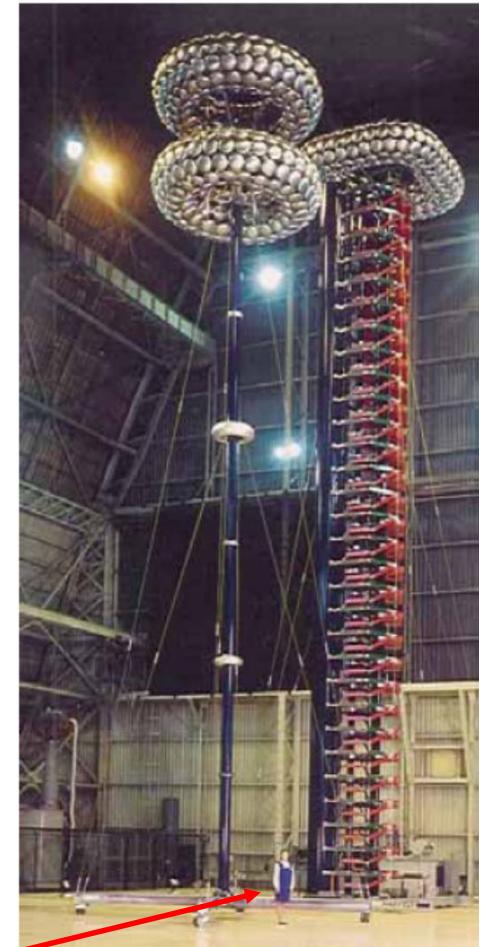


**Fig. 7.1** Impulse voltages

a) Square impulse voltage; b) wedge impulse voltage; c) double exponential impulse voltage

- Lightning impulse voltage:  $0 \rightarrow \hat{U}$  in approximately  $1 \mu\text{s}$
- Switching impulse voltage:  $0 \rightarrow \hat{U}$  after at least app.  $100 \mu\text{s}$

Impulse voltages for HV testing are standardized by means of IEC 60-2.



There's the man ☺

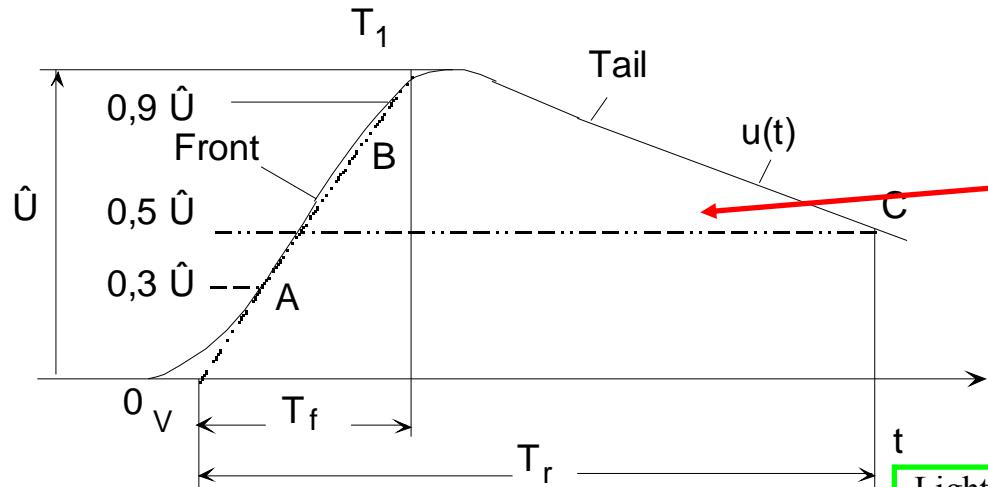
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## ● Rated values for lightning- and switching impulse voltages

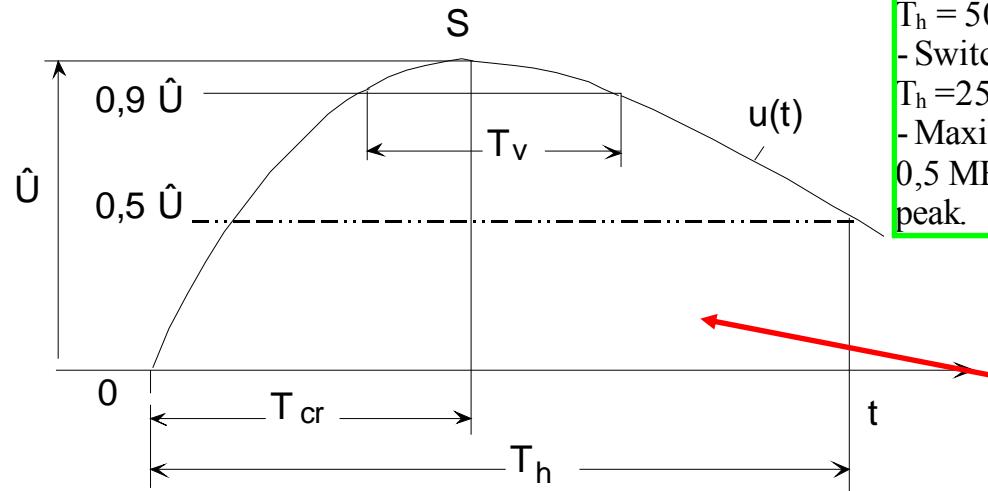


a)



Lightning impulse voltage

b)

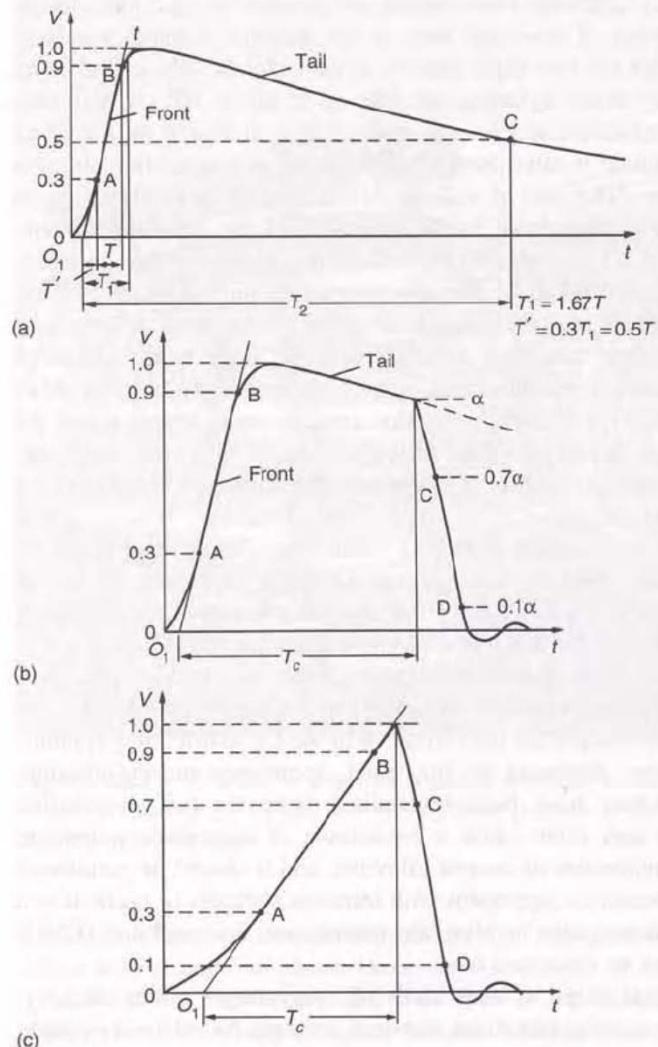


Switching impulse voltage

- Lightning impulse voltage:  $1,2/50 \mu\text{s}$ ,  $T_f = 1,2 \mu\text{s} +/- 30\%$  and  $T_h = 50 \mu\text{s} +/- 20\%$
- Switching impulse voltage:  $250/2500 \mu\text{s}$ ,  $T_{cr} = 250 \mu\text{s} +/- 20\%$  and  $T_h = 2500 \mu\text{s} +/- 60\%$
- Maximum content of high frequency oscillations:  $< 0,05 \times \hat{U}$  with  $f > 0,5 \text{ MHz}$ . With  $f < 0,5 \text{ MHz}$  one has to take  $\hat{U} = \text{actual highest voltage peak}$ .

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**Figure 2.23** General shape and definitions of lightning impulse (LI) voltages. (a) Full LI. (b) LI chopped on the tail. (c) LI chopped on the front.  
 $T_1$ : front time.  $T_2$ : time to half-value.  $T_c$ : time to chopping.  $O_1$ : virtual origin

disruptive discharge. Although the definitions are clearly indicated, it should be emphasized that the 'virtual origin'  $O_1$  is defined where the line  $AB$  cuts the time axis. The 'front time'  $T_1$ , again a virtual parameter, is defined as 1.67 times the interval  $T$  between the instants when the impulse is 30 per cent and 90 per cent of the peak value for full or chopped lightning impulses.

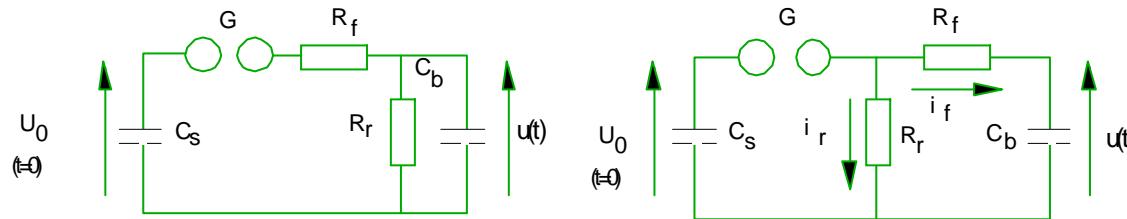
**QUESTION ??? ☺**  
**How does front chopping arise**  
**Why is it relevant**

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**● Capacitive circuits for impulse voltage supply**

The most important basic circuits are pronounced type a and type b, respectively.



We must discuss  
how this works !

Circuit type **a****Fig. 7.3** Basic circuits used to generate impulse voltages.Circuit type **b**

Components for the basic circuits:

- $C_s$  is the discharge capacitor
- G is the spark gap
- $R_f$  is the damping resistor (for shaping the front)
- $R_r$  is the discharge resistor (for shaping the tail)
- $C_b$  is the load capacitor (the capacitance of the EUT)

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## Utilization factor (efficiency) and discharge energy



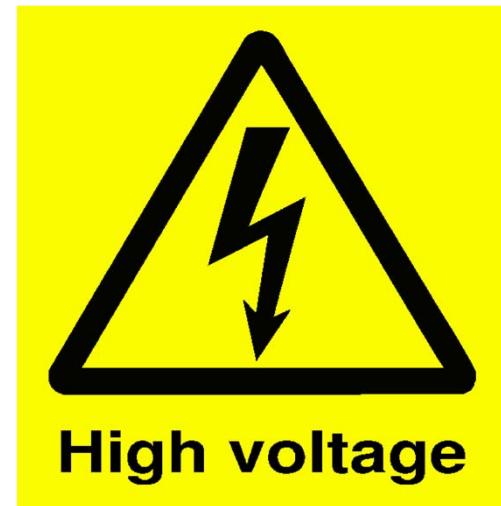
- Utilization factor

$$\eta = \frac{\hat{U}}{U_o} \leq \frac{C_s}{C_s + C_b}$$

For circuit b, simplified

- Maximum discharge energy

$$W = \frac{1}{2} C_s \cdot U_o^2 \quad [J]$$



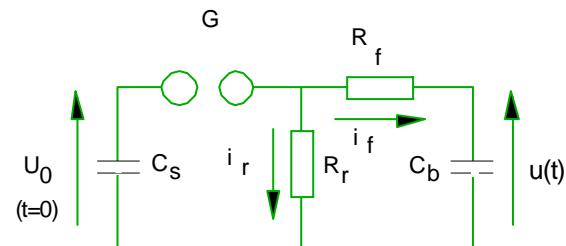
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**● Calculation of single stage impulse voltage circuits**

The components of the impulse voltage circuit must be designed well to create the desired impulse voltage waveform, ie. a 1,2/50  $\mu\text{s}$  lightning impulse voltage.

Basic circuit b is normally used, because of a higher possible utilization factor.

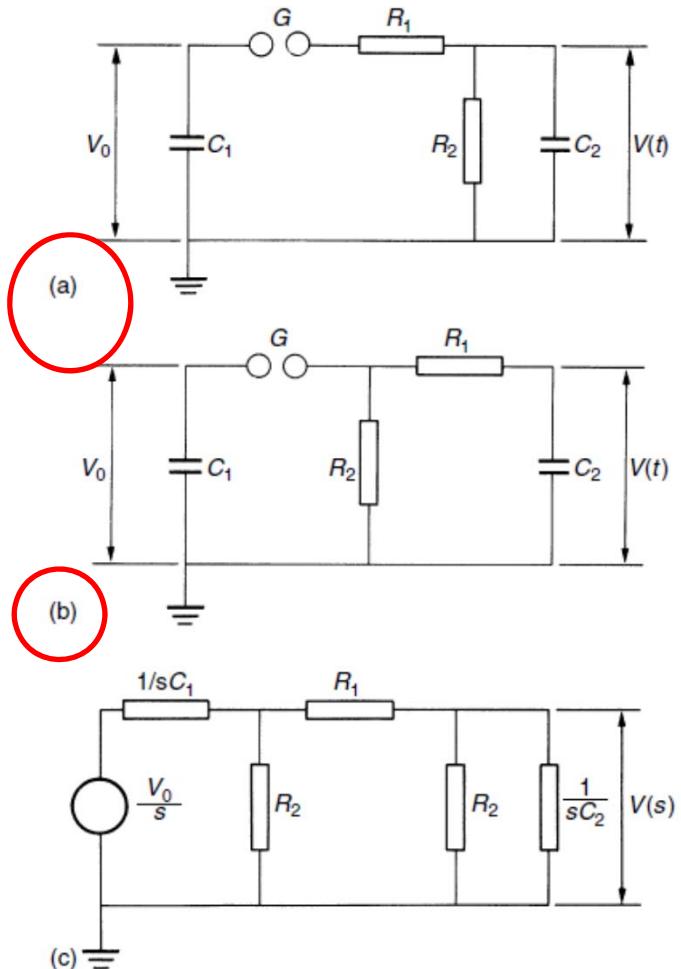


Kirchhoff's 2. law (KVL) gives:

$$U_o - \frac{1}{C_s} \int_o^t (i_r + i_f) dt = i_r R_r = i_f R_f + u(t) \quad V$$

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**Figure 2.25** Single-stage impulse generator circuits (a) and (b).  $C_1$ : discharge capacitance.  $C_2$ : load capacitance.  $R_1$ : front or damping resistance.  $R_2$ : discharge resistance. (c) Transform circuit

$$V(s) = \frac{V_0}{s} \frac{Z_2}{Z_1 + Z_2},$$

where

$$Z_1 = \frac{1}{C_1 s} + R_1;$$

$$Z_2 = \frac{R_2/C_2 s}{R_2 + 1/C_2 s}.$$

Laplace domain ☺

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By substitution we find

$$V(s) = \frac{V_0}{k} \frac{1}{s^2 + as + b}$$

where

$$a = \left( \frac{1}{R_1 C_1} + \frac{1}{R_1 C_2} + \frac{1}{R_2 C_2} \right);$$

$$b = \left( \frac{1}{R_1 R_2 C_1 C_2} \right);$$

$$k = R_1 C_2.$$

Output voltage a)

Depends on chosen components in the impulse generator and the "load".

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For circuit Fig. 2.25(b) one finds the same general expression (eqn (2.23)), with the following constants; however,

$$\begin{aligned} a &= \left( \frac{1}{R_1 C_1} + \frac{1}{R_1 C_2} + \frac{1}{R_2 C_1} \right); \\ b &= \left( \frac{1}{R_1 R_2 C_1 C_2} \right); \\ k &= R_1 C_2. \end{aligned} \quad \text{as above} \tag{2.25}$$

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For both circuits, therefore, we obtain from the transform tables the same expression in the time domain:

$$V(t) = \frac{V_0}{k} \frac{1}{(\alpha_2 - \alpha_1)} [\exp(-\alpha_1 t) - \exp(-\alpha_2 t)] \quad (2.26)$$

We recognize the output voltage to be the difference between two exponentials

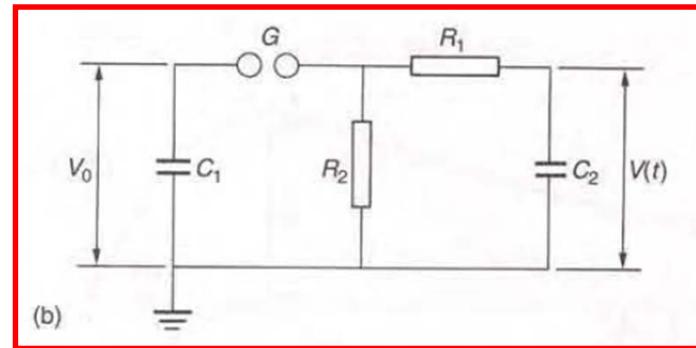
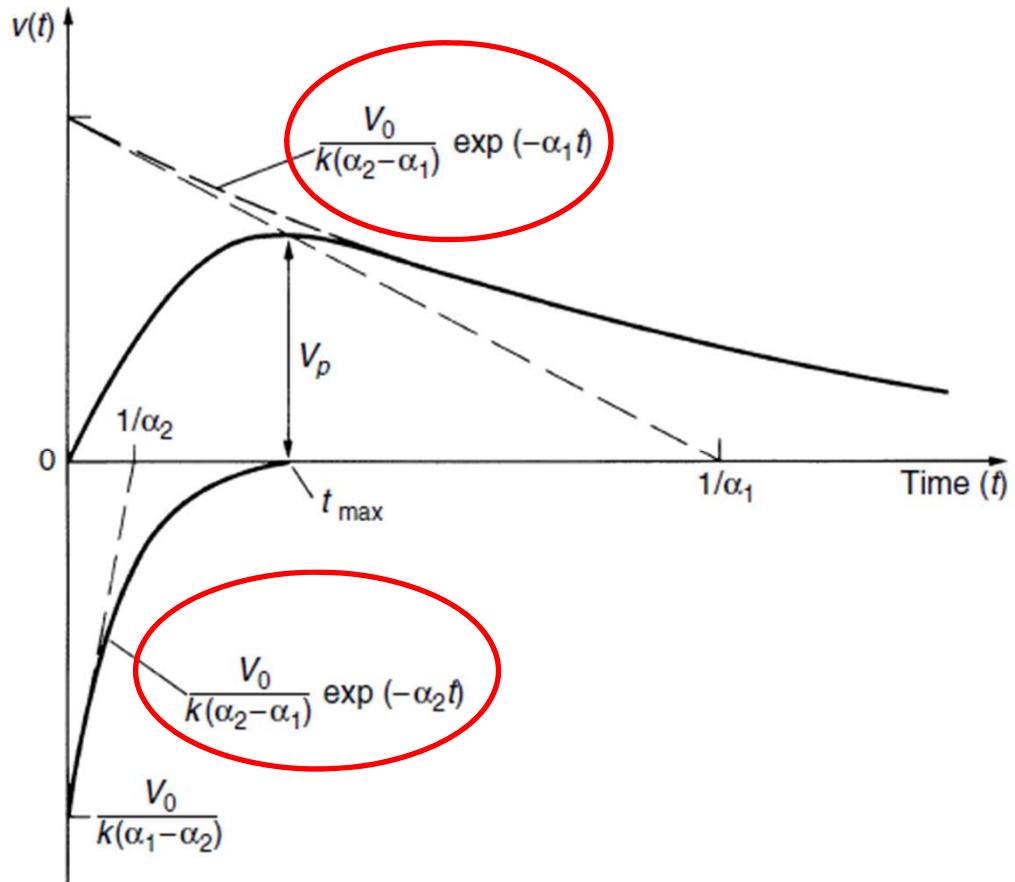
where  $\alpha_1$  and  $\alpha_2$  are the roots of the equation  $s^2 + as + b = 0$ , or

$$\alpha_1, \alpha_2 = \frac{a}{2} \mp \sqrt{\left(\frac{a}{2}\right)^2 - b}.$$

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## Output impulse voltage – doubly exponential



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Although one might assume that both circuits are equivalent, a larger difference may occur if the voltage efficiency,  $\eta$ , is calculated. This efficiency is defined as

$$\eta = \frac{V_p}{V_0}; \quad (2.28)$$

$V_p$  being the peak value of the output voltage as indicated in Fig. 2.26. Obviously this value is always smaller than 1 or 100 per cent. It can be calculated

WHY – obviously? ☺

by finding  $t_{\max}$  from  $dV(t)/dt = 0$ ; this time for the voltage  $V(t)$  to rise to its peak value is given by

$$t_{\max} = \frac{\ln(\alpha_2/\alpha_1)}{(\alpha_2 - \alpha_1)}. \quad (2.29)$$

Substituting this equation into eqn (2.26), one may find

$$\eta = \frac{(\alpha_2/\alpha_1)^{-[(\alpha_2/\alpha_1 - \alpha_1)]} - (\alpha_2/\alpha_1)^{-[(\alpha_2/\alpha_2 - \alpha_1)]}}{k(\alpha_2 - \alpha_1)}. \quad (2.30)$$

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For a given impulse shape  $T_1/T_2$  or  $T_p/T_2$  of the impulse voltages the values of  $\alpha_1$  and  $\alpha_2$  must be equal. The differences in efficiency  $\eta$  can only be due, therefore, to differences in the value of  $k = R_1 C_2$  for both circuits. We may first calculate this term for the circuit Fig. 2.25(b), which has always a higher efficiency for a given ratio of  $C_2/C_1$ , as during the discharge the resistors  $R_1$  and  $R_2$  do not form a voltage-dividing system. The product  $R_1 C_2$  is found by eqn (2.27) by forming

$$\alpha_1 \cdot \alpha_2 = b$$

$$\alpha_1 + \alpha_2 = a \quad (2.31)$$

and by the substitution of  $a$  and  $b$  from eqn (2.25). Then we obtain

$$k = R_1 C_2 = \frac{1}{2} \left( \frac{\alpha_2 + \alpha_1}{\alpha_2 \cdot \alpha_1} \right) \left[ 1 - \sqrt{1 - 4 \frac{\alpha_2 \cdot \alpha_1}{(\alpha_2 + \alpha_1)^2} \left( 1 + \frac{C_2}{C_1} \right)} \right]. \quad (2.32)$$

For  $C_2 \leq C_1$ , which is fulfilled in all practical circuits, and with  $\alpha_2 \gg \alpha_1$  for all normalized waveshapes, one may simplify this equation to

$$k \cong \frac{1 + C_2/C_1}{(\alpha_2 + \alpha_1)}. \quad (2.33)$$

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For circuit b)

The substitution of this expression in eqn (2.30) finally results in

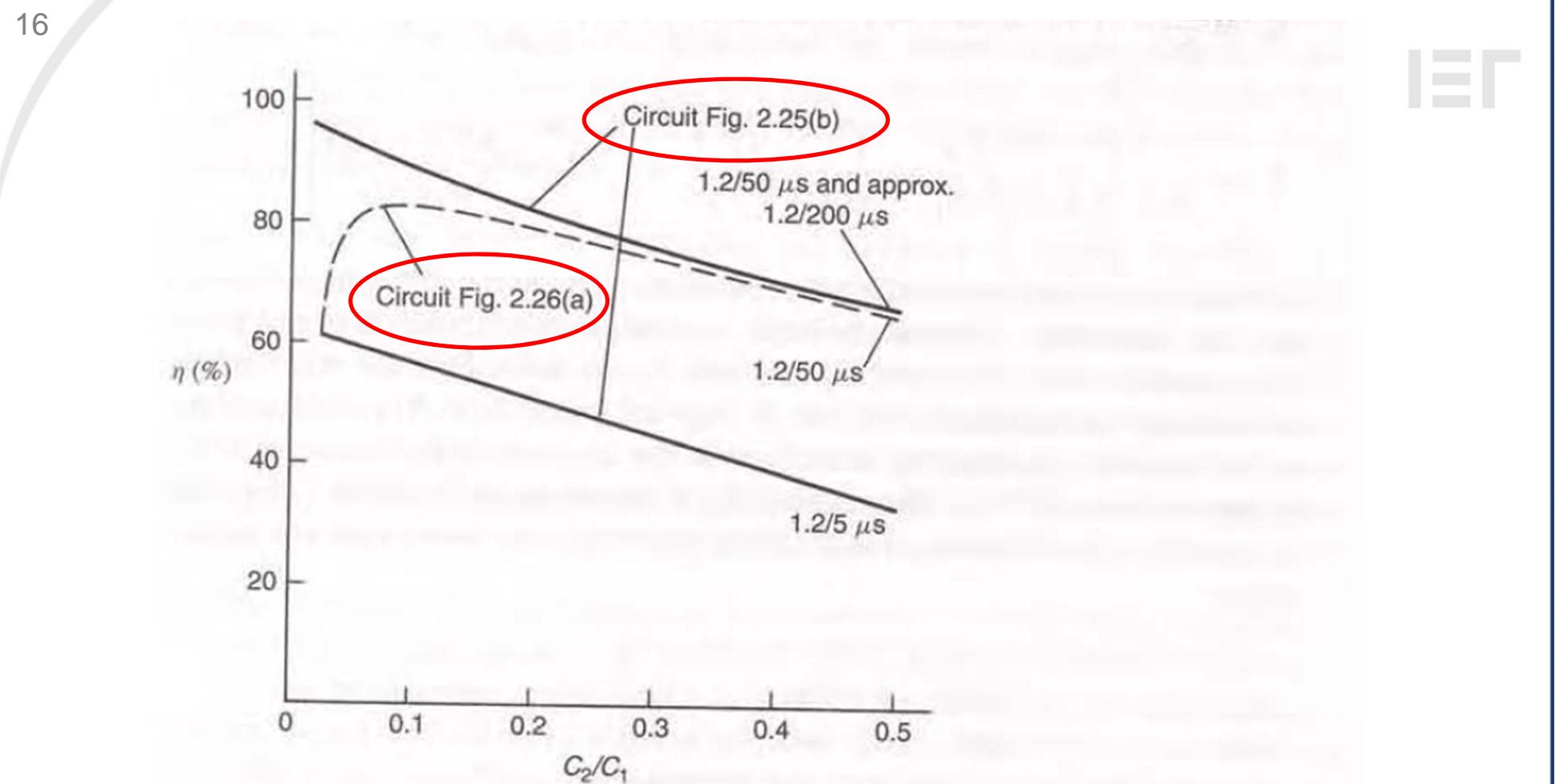
$$\eta = \frac{C_1}{(C_1 + C_2)} = \frac{1}{1 + (C_2/C_1)}$$

For circuit a)

$$\eta \approx \frac{C_1}{(C_1 + C_2)(R_1 + R_2)} \frac{R_2}{(1 + C_2/C_1)} = \frac{1}{(1 + C_2/C_1)} \frac{1}{(1 + R_1/R_2)}.$$

Voltage dividing because of resistor R<sub>2</sub> location

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**Figure 2.27** Voltage efficiency factors  $\eta$  in dependency of the capacitance ratio  $C_2/C_1$  for lightning impulses  $T_1/T_2$

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$$R_1 = \frac{1}{2C_1} \left[ \left( \frac{1}{\alpha_1} + \frac{1}{\alpha_2} \right) - \sqrt{\left( \frac{1}{\alpha_1} + \frac{1}{\alpha_2} \right)^2 - \frac{4(C_1 + C_2)}{\alpha_1 \alpha_2 \cdot C_2}} \right]. \quad (2.36)$$

$$R_2 = \frac{1}{2(C_1 + C_2)} \left[ \left( \frac{1}{\alpha_1} + \frac{1}{\alpha_2} \right) + \sqrt{\left( \frac{1}{\alpha_1} + \frac{1}{\alpha_2} \right)^2 - \frac{4(C_1 + C_2)}{\alpha_1 \alpha_2 C_2}} \right]. \quad (2.37)$$

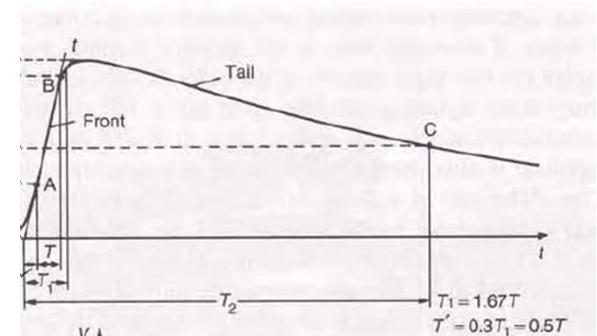
**Circuit Fig. 2.25(b):**

$$R_1 = \frac{1}{2C_2} \left[ \left( \frac{1}{\alpha_1} + \frac{1}{\alpha_2} \right) - \sqrt{\left( \frac{1}{\alpha_1} + \frac{1}{\alpha_2} \right)^2 - \frac{4(C_1 + C_2)}{\alpha_1 \alpha_2 C_1}} \right]. \quad (2.38)$$

$$R_2 = \frac{1}{2(C_1 + C_2)} \left[ \left( \frac{1}{\alpha_1} + \frac{1}{\alpha_2} \right) + \sqrt{\left( \frac{1}{\alpha_1} + \frac{1}{\alpha_2} \right)^2 - \frac{4(C_1 + C_2)}{\alpha_1 \alpha_2 C_1}} \right]. \quad (2.39)$$

All these equations contain the time constants  $1/\alpha_1$  and  $1/\alpha_2$ , which depend upon the waveshape. There is, however, no simple relationship between these time constants and the times  $T_1$ ,  $T_2$  and  $T_p$  as defined in the national or international recommendations, i.e. in Figs 2.23 and 2.24. This relationship can be found by applying the definitions to the analytical expression for  $V(t)$ , this means to eqn (2.26). The relationship is irrational and must be computed numerically. The following table shows the result for some selected wave-shapes:

	$T_1/T_2$ (μs)	$T_p/T_2$ (μs)	$1/\alpha_1$ (μs)	$1/\alpha_2$ (μs)
1.2/5	—	—	3.48	0.80
1.2/50	—	—	68.2	0.405
1.2/200	—	—	284	0.381
250/2500	—	—	2877	104
—	250/2500	3155	—	62.5



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The standardized nominal values of  $T_1$  and  $T_2$  are difficult to achieve in practice, as even for fixed values of  $C_1$  the load  $C_2$  will vary and the exact values for  $R_1$  and  $R_2$  according to eqns (2.38) and (2.39) are in general not available. These resistors have to be dimensioned for the rated high voltage of the generator and are accordingly expensive. The permissible tolerances for  $T_1$  and  $T_2$  are therefore necessary and used to graduate the resistor values. A recording of the real output voltage  $V(t)$  will in addition be necessary if the admissible impulse shape has to be testified.

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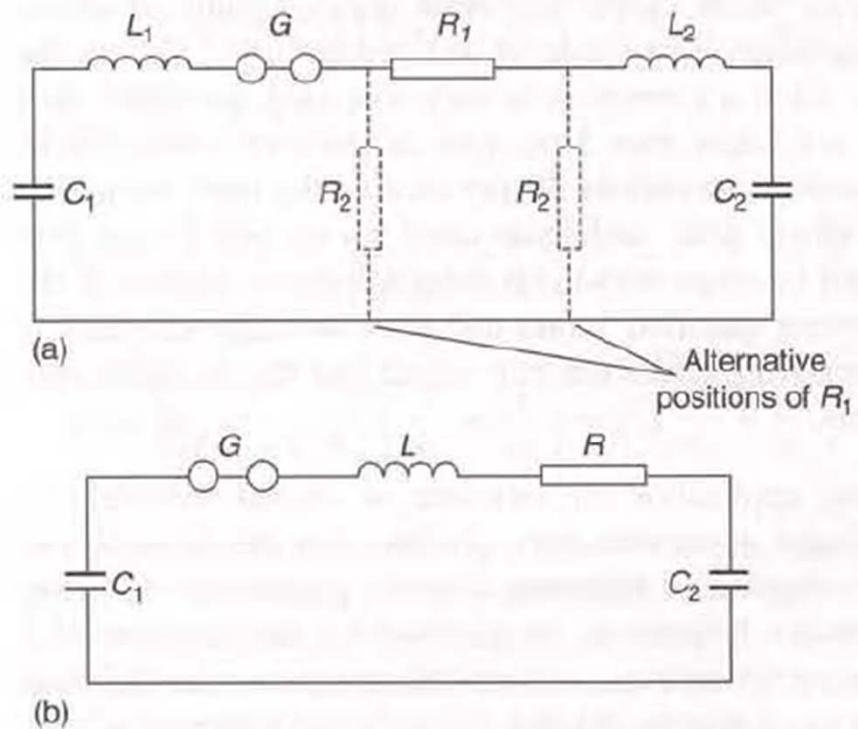
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Another reason for such a measurement is related to the value of the test voltage as defined in the recommendations.<sup>(2,3)</sup> This magnitude corresponds to the crest value, if the shape of the lightning impulse is smooth. However, oscillations or an overshoot may occur at the crest of the impulse. If the frequency of such oscillations is not less than 0.5 MHz or the duration of overshoot not over 1  $\mu$ sec, a ‘mean curve’ (see Note below) should be drawn through the curve. The maximum amplitude of this ‘mean curve’ defines the value of the test voltage. Such a correction is only tolerated, provided their single peak amplitude is not larger than 5 per cent of the crest value. Oscillations on the front of the impulse (below 50 per cent of the crest value) are tolerated, provided their single peak amplitude does not exceed 25 per cent of the crest value. It should be emphasized that these tolerances constitute the permitted differences between specified values and those actually recorded by measurements. Due to measuring errors the true values and the recorded ones may be somewhat different.

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$$R_1 \cong R = 2\sqrt{\frac{L}{C}}$$

where

$$\frac{1}{C} = \frac{1}{C_1} + \frac{1}{C_2}$$

For a non-oscillatory behavior.

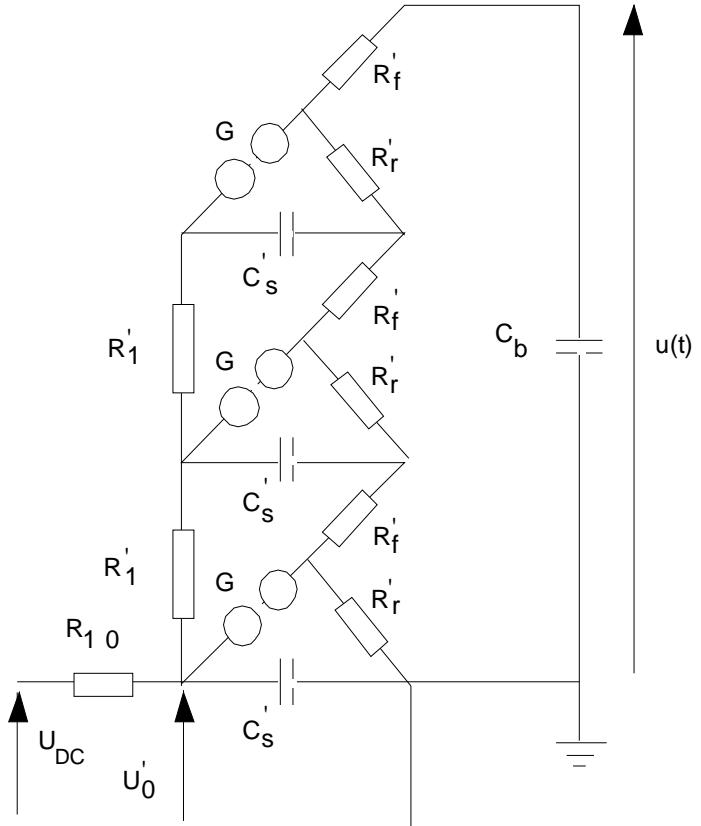
Critically damped!

**Figure 2.28** Simplified circuit of impulse generator and load. Circuit showing alternative positions of the wave tail control resistance. (b) Circuit for calculation of wave front oscillations

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## Cascaded impulse generator (Marx generator)



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R' charging resistor  
C' stage capacitors  
R<sub>2</sub> discharge resistors  
R<sub>1</sub> external discharge resistor

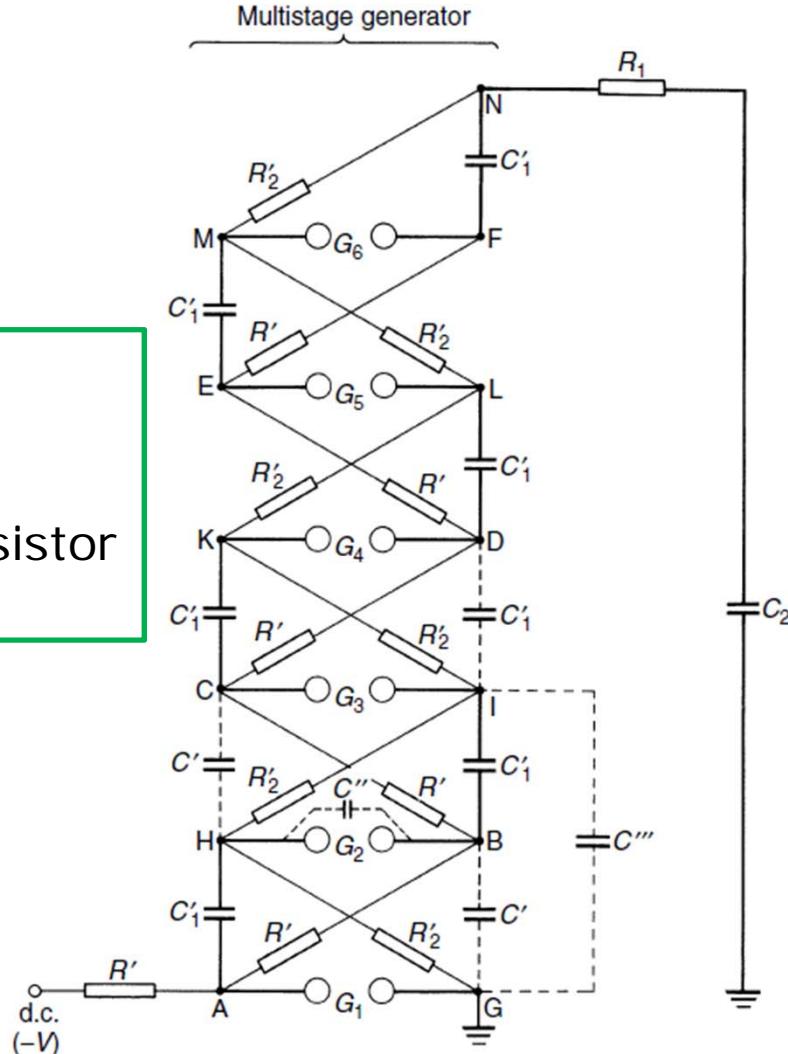
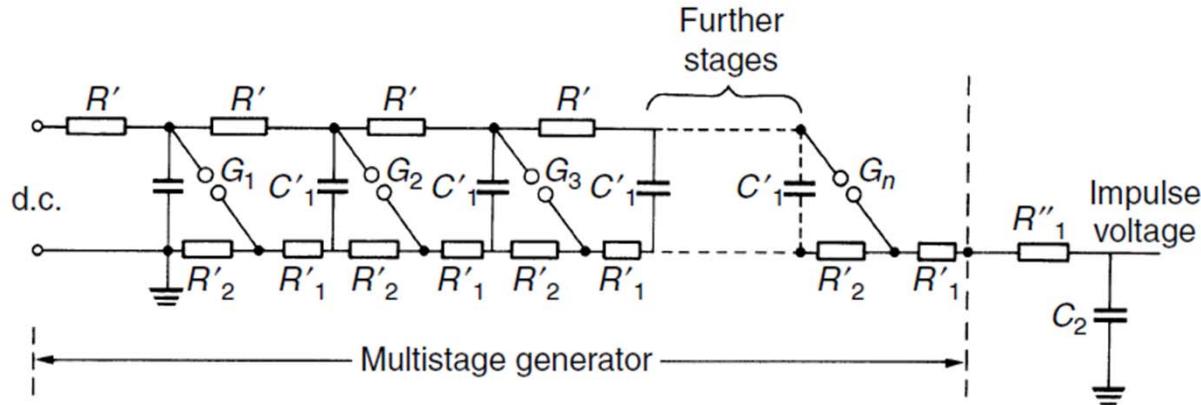


Figure 2.29 Basic circuit of a six-stage impulse generator (Marx generator)

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**Figure 2.30** Multistage impulse generator with distributed discharge and front resistors.  $R'_2$ : discharge resistors.  $R'_1$ : internal front resistors.  $R''_1$ : external front resistor

$$\frac{1}{C_1} = \sum_{i=1}^n \frac{1}{C'_i};$$

the effective front resistance  $R_1$  as

$$R_1 = R''_1 + \sum_{i=1}^n R'_i;$$

and the effective discharge resistance  $R_2$  – neglecting the charging resistances  $R'$  – as

$$R_2 = nR'_2 = \sum_{i=1}^n R'_2;$$

where  $n$  is the number of stages.

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- **Measurement of impulse peak voltage by means of measuring sphere gaps**

The breakdown of gases in a quasihomogeneous electric field will develop within very few microseconds ( $1\text{-}2 \mu\text{s}$ ), typically nanoseconds, measured from the time, where the voltage rises above the breakdown voltage  $U_d$ .

This quality makes it feasible to measure the peak voltage of an impulse voltage by means of a sphere gap, as long as the tail half-life time  $T_r > 50 \mu\text{s}$ .

The measuring accuracy will be comparable to the measuring accuracy with AC-voltages, ie. below 3 %

The breakdown time delay will consist of a statistical and a formative time for the gas discharge to develop.



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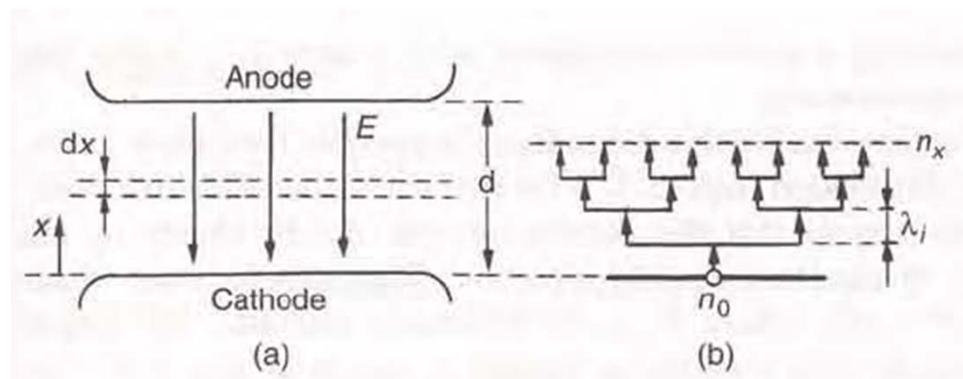
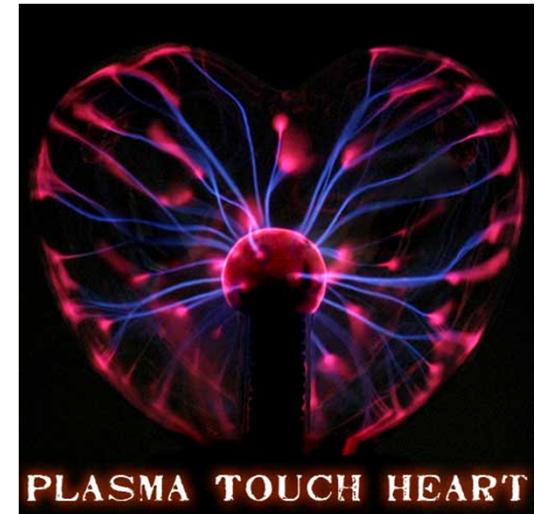
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- The statistical time delay is determined by the time elapsed from the moment of the voltage impression and to the presence of an initial electron at the place in the field space comprising the maximum field strength.

The statistical time delay can practically be eliminated by means UV-illumination or radioactive radiation of the cathode.

- The formative time delay is determined by the physical development time for the electron avalanche to pass the electrode gap. It depends, among other things, of the gap length.



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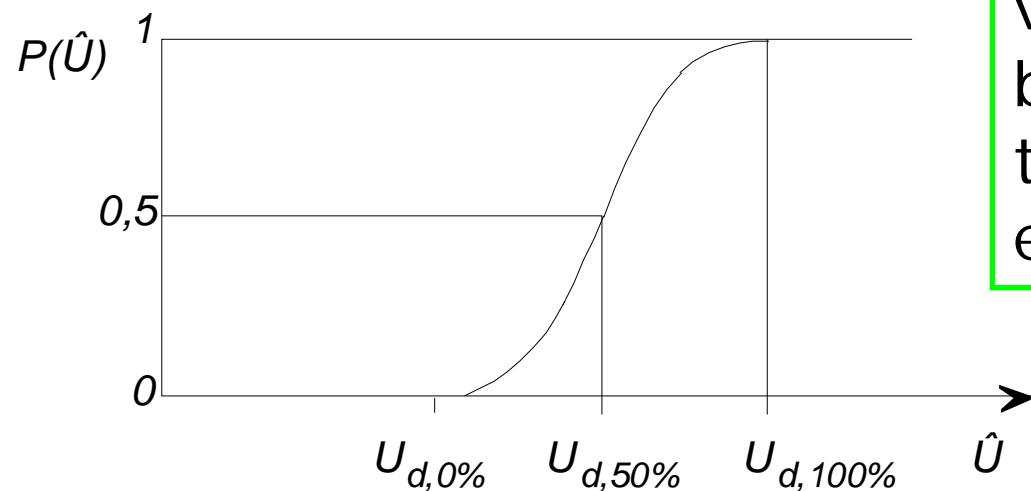
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**● 50 % breakdown voltage**

Sphere gap breakdown voltage tables (ie. from IEC60-2) give the so called standard atmospherically (nominal air density) converted 50 % breakdown voltage  $\hat{U}_{d,0}$ .

The following relation apply for impulse voltages:

$$U_{d,50\%} \approx \hat{U}_d \approx d \hat{U}_{d,0}$$

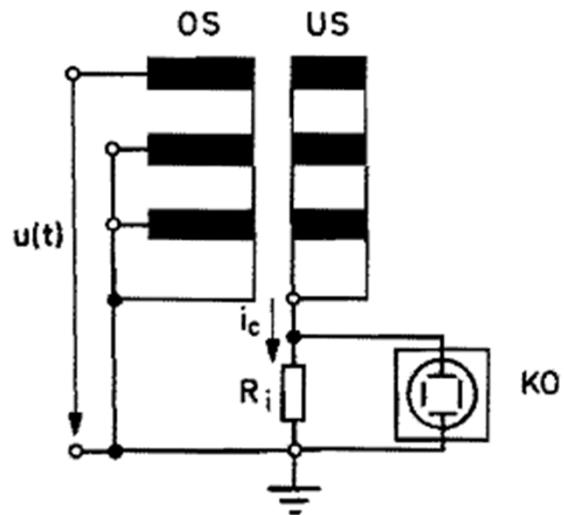


So for impulse voltages we **ALWAYS** mean the 50% breakdown voltage when using breakdown voltage tables or when nothing else is stated !

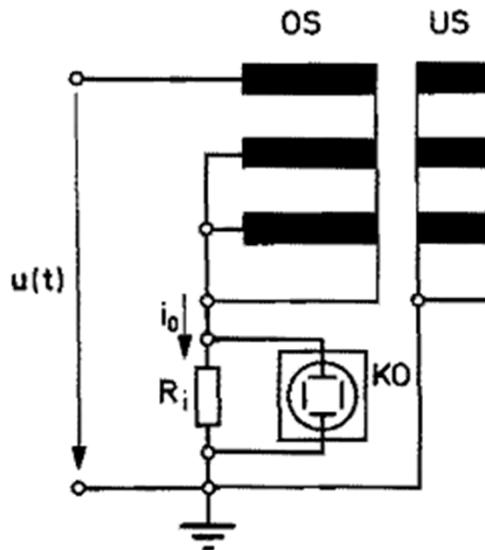
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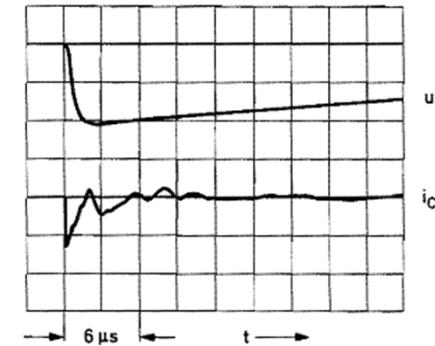
Tell a story about the testing of large Power transformers ☺

**Bild 3.9-4**

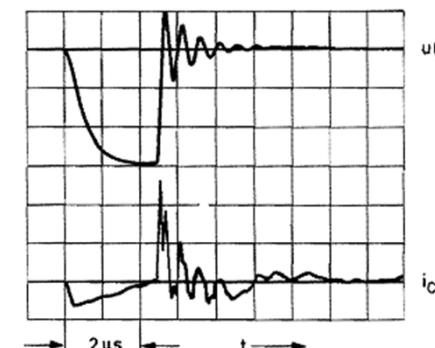
Schaltung zur Prüfung mit Blitzstoßspannung nach Eisner  
OS Oberspannungswicklung,  
US Unterspannungswicklung

**Bild 3.9-5**

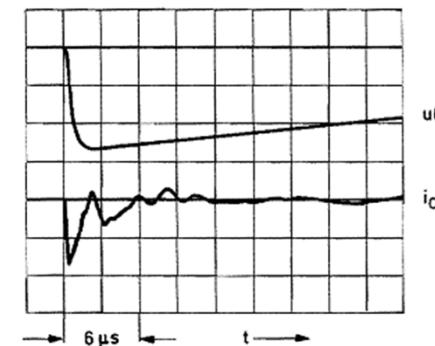
Schaltung zur Prüfung mit Blitzstoßspannung nach Hagenguth  
OS Oberspannungswicklung,  
US Unterspannungswicklung



Reduced wave  
 $u(t)$   
 $i_c(t)$



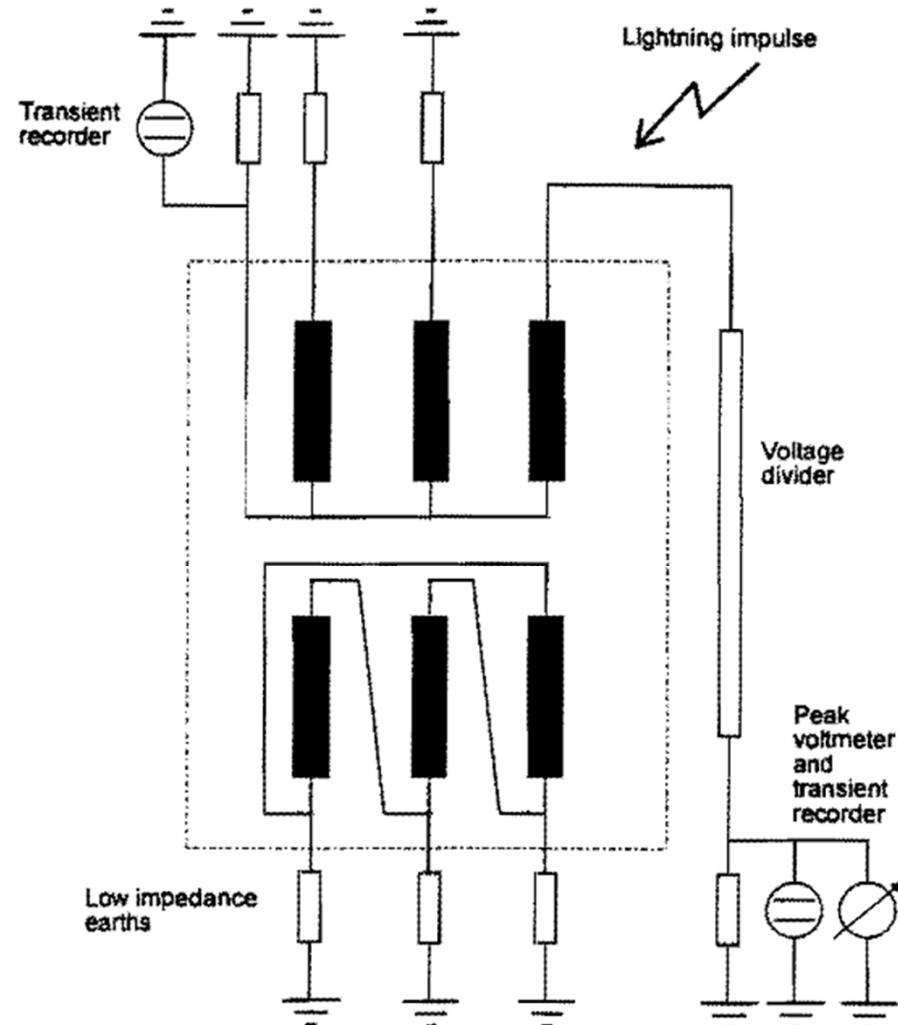
Chopped wave  
 $u(t)$   
 $i_c(t)$



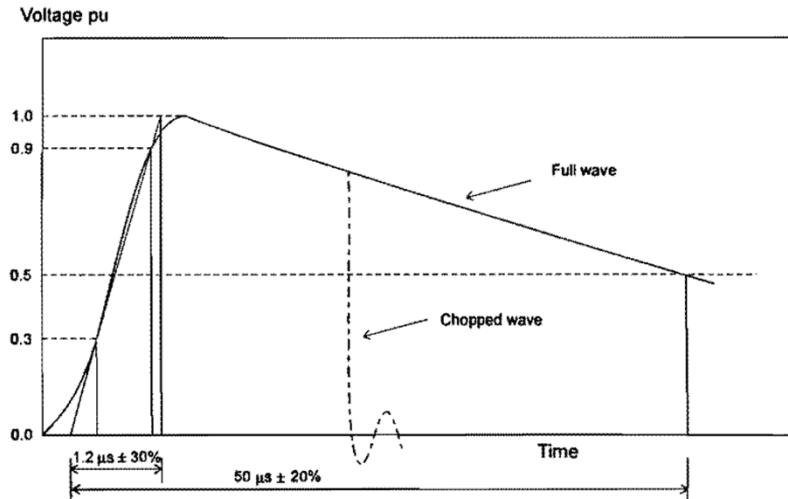
Control with  
full wave  
 $u(t)$   
 $i_c(t)$

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*Lightning impulse test arrangement*



*Fig. 10.6 Lightning impulse wave shape*

The test sequence required by NGC for routine tests on every unit, at the voltage level specified in Table 10.2, is:

- (i) 1 Reduced full wave (between 50 and 75 %);
- (ii) 1 Full wave (100 %);
- (iii) 2 Chopped waves (115 %);
- (iv) 2 Full waves (100 %);
- (v) 1 Reduced full wave (at same level as first impulse).

Transient recordings of the applied voltage and of the current at the neutral end of the winding under test are taken.

The transformer passes the test if there is no evidence of complete or incipient failure from audible indications or changes in the voltage or current records.